## **Generic EEPROM driver library**

## Guide

Visibility and dissemination of the document:

#### Can be widely distributed

Language: C

Language version: **C99** Endianness: **Little endian only** 

Synchronous: **yes**Asynchronous: **no**OS: **need adaptation** 

MCU compatibility: **no limit except endianness** 

Tests: full

MISRA C: to be determined CERT C: to be determined

PBIT: yes CBIT: possible

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# Generic I2C EEPROM driver library

Version: 1.0.0 date: 24 August 2020

This library has been tested and is compatible with components:

- AT24C01, AT24C02, AT24C04, AT24C08, AT24C16
- 24xx256
- AT24MACx02 (only EEPROM part)
- 47L/C04, 47L/C16 (only RAM/EEPROM part)

This library is fully compatible with I2C EEPROMs with an address 1010xxx\_compatibility

| Established by       | Reviewed             | Approved             |
|----------------------|----------------------|----------------------|
| Name: FMA            | Name: FMA            | Name: FMA            |
| Date: 24 August 2020 | Date: 24 August 2020 | Date: 24 August 2020 |

|       |                | Change history   |           |        |
|-------|----------------|------------------|-----------|--------|
| Issue | Date           | Nature / comment | Paragraph | Writer |
| 1.0.0 | 24 August 2020 | Initial release  | -         | FMA    |

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Table summary

Aucune entrée de table d'illustration n'a été trouvée.

#### 1. INTRODUCTION

#### 1.1. Purpose

The purpose of this document is to explain how the driver library works and how to use it. It can work with every memory with an address 1010xxx compatibility.

#### The driver features are:

- Can be use with any MCU if its CPU use little endian
- Only take care of the memory, not the communication with it
- All functions and functionalities are implemented
- Configuration is very simplified
- Can communicate with virtually an infinite count of memories
- Different configurations can be used with different memories (no duplication of the driver needed)
- Direct communication with the memories, the driver has no buffer
- Can use the driver defines, enums, structs to create your own functions
- Contiguous memories can be used as 1 unique memory by the driver (under certain conditions)
- Driver will take care of page access to minimize write process and save time
- Driver will take care of address composition of the data

#### 1.2. Documents, References, and abbreviations

#### 1.2.1. Applicable documents

| IDENTIFICATION | TITLE | DATE |
|----------------|-------|------|
| -              | -     | -    |

#### 1.2.2. Reference documents

| IDENTIFICATION | TITLE | DATE |
|----------------|-------|------|
| -              |       | -    |

#### 1.2.3. Abbreviations and Acronyms

This is the list of all the abbreviations and acronyms used in this document and their definitions. They are arranged in alphabetical order.

| CBIT  | Continuous Built-In Test                        |
|-------|---|
| CERT  | Computer Emergency Response Team                |
| CLK   | Clock   |
| I2C   | Inter-Integrated Circuit                        |
| MCU   | Micro-Controller Unit                           |
| MISO  | Master In Slave Out                             |
| MISRA | Motor Industry Software Reliability Association |
| MOSI  | Master Out Slave In                             |
| OS    | Operating System                                |
| PBIT  | Power Up Built-In Test                          |
| PIO   | Programmable Input/Output                       |
| RAM   | Random Access Memory                            |
|       |   |

#### 2. PRESENTATION

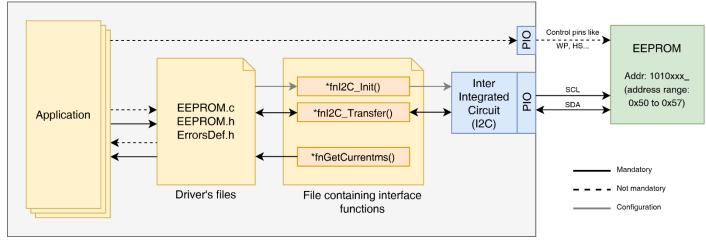


Figure 1 - Driver overview

This driver only takes care of configuration and check of the internal registers and the formatting of the communication with the device. That means it does not directly take care of the physical communication, there is functions interfaces to do that.

Each driver's functions need a device structure that indicate with which device he must threat and communicate and the configuration of the memory. Each device can have its own configuration.

#### 2.1. Setup

To set up one or more devices in the project, you must:

- Create a memory configuration (only one per device part number because they can be shared)
- Create and define the configuration of as many device structures as there are devices to use

#### 2.2. Contiguous memories

The driver can use multiple devices as only one "virtual memory". To do this, you need to take into account some limitation of the possibility. Devices needs:

- Memories shall be on the same I2C bus
- Addressing to use all bits in the address bytes of the device i.e.:
  - o If 1-byte address, the device uses 8, 9, 10 bits
  - o If 2-bytes address, the device uses 16, 17, 18 bits
  - o If 3-bytes address, the device uses 24, 25, 26 bits
- No unused bits in place of A0, A1, and A2 in the device chip address i.e., fixed as '0' or '1'
- Chip addresses shall follow each other and start at the lowest Ax possible chip address pin
- Shall have 2<sup>x</sup> component

#### 3. MEMORY CONFIGURATION

To work with a memory, the driver needs to know:

- How to address the device
- How the memory address is composed to access data
- The memory size
- The memory page size (if any)
- Time to write memory (for timeout purpose)

The device configuration type is **EEPROM\_Conf**. All information to fill the structure can be found in the datasheet of the target device.

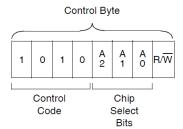
#### 3.1. Example of how to fill an EEPROM\_Conf of a device with A0, A1 and A2 pins

The following example was performed on a 24LC256 device.

```
const EEPROM_Conf _24LC256_Conf =
  .ChipAddress
                 = 0 \times A0,
                                                // Chip base address
                 = EEPROM_CHIP_ADDRESS_A2A1A0, // Device have A2, A1 and A0 pins
 .ChipSelect
  .AddressType
                = EEPROM_ADDRESS_2Bytes,
                                                // Memory address takes 2 bytes
 .PageWriteTime = 5,
                                                // 5ms of page write
                = 64
 .PageSize
                                                // Page size is 64 bytes
  .ArrayByteSize = 512/*Pages*/ *64,
                                                // Memory size is 512*64 = 32768 bytes
  .MaxI2CclockSpeed = 400000,
                                                // Max I2C SCL speed is 400kHz
```

#### 3.1.1. Fill the EEPROM\_Conf.ChipAddress

In the 24LC256 datasheet, the information is indicated at §5.0 "DEVICE ADDRESSING" in the Figure 5-2:



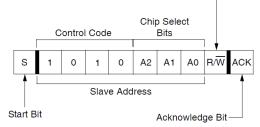
We are looking for the fixed information called here "Control Code", without A2, A1, and A0 bits. The  $R/\overline{W}$  bit need to be ignored too. These bits have to be set to '0'. So, we configure EEPROM\_Conf.ChipAddress with 0b10100000 or 0xA0.

#### 3.1.2. Fill the EEPROM\_Conf.ChipSelect

Here we are looking for which chip select bits are present on this device. In the 24LC256 datasheet, the information is indicated at §2.0 "PIN DESCRIPTIONS" in Table 2-1 and at §5.0 "DEVICE ADDRESSING" in the Figure 5-1:

Read/Write Bit—

| Name | 8-pin<br>PDIP | 8-pin<br>SOIC | 8-pin<br>TSSOP | 14-pin<br>TSSOP | 8-pin<br>MSOP | 8-pin<br>DFN | Function                      |
|------|---------------|---------------|----------------|-----------------|---------------|--------------|-------------------------------|
| A0   | 1             | 1             | 1              | 1               | _             | 1            | User Configurable Chip Select |
| A1   | 2             | 2             | 2              | 2               | _             | 2            | User Configurable Chip Select |
| (NC) | _             | _             | _              | 3, 4, 5         | 1, 2          | <b>—</b>     | Not Connected                 |
| A2   | 3             | 3             | 3              | 6               | 3             | 3            | User Configurable Chip Select |

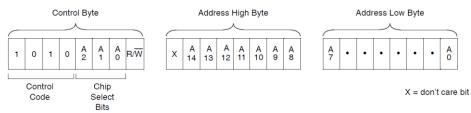


The device has A0, A1, and A2 as user configurable chip select. They are all configurable at '0' or '1'.

So, we configure EEPROM Conf.ChipSelect with EEPROM CHIP ADDRESS A2A1A0.

#### 3.1.3. Fill the EEPROM\_Conf.AddressType

In the 24LC256 datasheet, the information is indicated at §5.0 "DEVICE ADDRESSING" in the Figure 5-2:



The address takes 2 bytes. The first is for "Address High Byte" and the second is for "Address Low Byte". So, we need to configure EEPROM Conf.AddressType with EEPROM ADDRESS 2Bytes.

#### 3.1.4. Fill the EEPROM\_Conf.PageWriteTime

In the 24LC256 datasheet, the information is indicated at §1.0 "ELECTRICAL CHARACTERISTICS" in the Table 1-2:

| AC CHARACTERISTICS (Continued) |     |                                 | Electrical Characteristics:   Industrial (I):   Vcc = +1.8V to 5.5V   TA = -40°C to +8   Automotive (E):   Vcc = +2.5V to 5.5V   TA = -40°C to +1 |     |       |   |            |
|--------------------------------|-----|---------------------------------|---|-----|-------|---|------------|
| Param.<br>No.                  | Sym | Characteristic                  | Min   | Max | Units |   | Conditions |
| 17                             | Twc | Write cycle time (byte or page) | _   | 5   | ms    | _ |            |

The parameter 17 indicate that the maximum write cycle time is 5ms. We need to always use the maximum time. So, we configure EEPROM\_Conf.PageWriteTime with 5.

#### 3.1.5. Fill the EEPROM\_Conf.PageSize

In the 24LC256 datasheet, the information is indicated in the Features of the device or the Description of the device in the first page of the datasheet:

• 64-byte Page Write mode available

So, we configure EEPROM Conf.PageSize with 64

#### 3.1.6. Fill the EEPROM Conf. Array ByteSize

In the 24LC256 datasheet, the information is indicated in the Description of the device in the first page of the datasheet:

#### Description

The Microchip Technology Inc. 24AA256/24LC256/24FC256 (24XX256\*) is a 32K x 8 (256 Kbit) Serial Electrically Erasable PROM, capable of operation

It is indicated 32K x 8 (256 Kbit). This memory is  $256 \times 1024 = 262144 \ bits \rightarrow 256144/8 = 32768 \ bytes$ . The memory organization is  $32768/64 = 512 \ page$  of 64 bytes

So, we configure EEPROM\_Conf.ArrayByteSize with 32768.

#### 3.1.7. Fill the EEPROM\_Conf.MaxI2CclockSpeed

In the 24LC256 datasheet, the information is indicated in the Device Selection Table of the device in the first page of the datasheet:

#### **Device Selection Table**

| Part<br>Number | Vcc<br>Range | Max. Clock<br>Frequency | Temp.<br>Ranges |
|----------------|--------------|-------------------------|-----------------|
| 24AA256        | 1.8-5.5V     | 400 kHz <sup>(1)</sup>  | ı               |
| 24LC256        | 2.5-5.5V     | 400 kHz                 | I, E            |
| 24FC256        | 1.8-5.5V     | 1 MHz <sup>(2)</sup>    | ı               |

It is indicated that the 24LC256 has an I2C Maximum Clock Frequency of 400kHz with no restriction of voltage. So, we configure EEPROM\_Conf.MaxI2CclockSpeed with 400000.

# 3.2. Example of how to fill an EEPROM\_Conf of a device with A0, A1 and A2 pins that can be address pin

The following example was performed on a AT24C08A device.

```
const EEPROM_Conf AT24C08A_Conf =
  .ChipAddress
                = 0xA0,
                                                   // Chip base address
                = EEPROM_CHIP_ADDRESS_A2,
 .ChipSelect
                                                   // Device have only the A2 pins
               = EEPROM_ADDRESS_1Byte_plus_A1A0, // Memory address takes 1 bytes + A0 and A1 pin function
 .AddressType
  .PageWriteTime = 5,
                                                   // 5ms of page write
 .PageSize
               = 16,
                                                   // Page size is 16 bytes
  .ArrayByteSize = 64/*Pages*/ *16,
                                                   // Memory size is 64*16 = 1024 bytes
  .MaxI2CclockSpeed = 400000,
                                                   // Max I2C SCL speed is 400kHz
```

The AT24C08A device is a "8K SERIAL EEPROM" as say in the datasheet:

AT24C08A, 8K SERIAL EEPROM: Internally organized with 64 pages of 16 bytes each, the 8K requires a 10-bit data word address for random word addressing.

#### 3.2.1. Fill the EEPROM\_Conf.ChipAddress

In the AT24C08A datasheet, the information is indicated in the Figure 7 "Device Address":



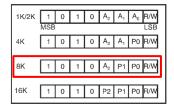
We are looking for the fixed information for the 8K device, without A2, P1, and P0 bits. The  $R/\overline{W}$  bit need to be ignored too. These bits have to be set to '0'. So, we configure EEPROM\_Conf.ChipAddress with 0b10100000 or 0xA0.

#### 3.2.2. Fill the EEPROM\_Conf.ChipSelect

Here we are looking for which chip select bits are present on this device. In the AT24C08A datasheet, the information is indicated at "PIN DESCRIPTION", at "DEVICE ADDRESSING" and in the Figure 7 "Device Address":

The AT24C08A only uses the A2 input for hardwire addressing and a total of two 8K devices may be addressed on a single bus system. The A0 and A1 pins are no connects and can be connected to ground.

The 8K EEPROM only uses the A2 device address bit with the next 2 bits being for memory page addressing. The A2 bit must compare to its corresponding hard-wired input pin. The A1 and A0 pins are no connect.



The device has only A2 as user configurable chip select. It is configurable at '0' or '1'. So, we configure EEPROM\_Conf.ChipSelect with EEPROM\_CHIP\_ADDRESS\_A2.

#### 3.2.3. Fill the EEPROM\_Conf.AddressType

With the information said in §3.2.2, the device uses A0 as 9<sup>th</sup> bit, and A1 as 10<sup>th</sup> bit of the addressing. So, we need to configure EEPROM\_Conf.AddressType with EEPROM\_ADDRESS\_1Byte\_plus\_A1A0.

#### 3.2.4. Fill the EEPROM\_Conf.PageWriteTime

In the AT24C08A datasheet, the information is indicated in Table 5 "AC Characteristics":

|                 |                  | 1.8- | volt | 2.7, 5 | .0-volt |       |
|-----------------|------------------|------|------|--------|---------|-------|
| Symbol          | Parameter        | Min  | Max  | Min    | Max     | Units |
| t <sub>WR</sub> | Write Cycle Time |      | 5    |        | 5       | ms    |

The parameter  $t_{WR}$  indicate that the maximum write cycle time is 5ms. We need to always use the maximum time. So, we configure EEPROM\_Conf.PageWriteTime with 5.

#### 3.2.5. Fill the EEPROM\_Conf.PageSize

In the AT24C08A datasheet, the information is indicated in the Memory Organization of the device:

AT24C08A, 8K SERIAL EEPROM: Internally organized with 64 pages of 16 bytes each, the 8K requires a 10-bit data word address for random word addressing.

So, we configure EEPROM Conf.PageSize with 16

#### 3.2.6. Fill the EEPROM\_Conf.ArrayByteSize

With the information said in §3.2.5:

It is indicated that the memory organization is 64 pages of 16 bytes = 1024 bytes

So, we configure EEPROM Conf. Array ByteSize with 1024.

#### 3.2.7. Fill the EEPROM\_Conf.MaxI2CclockSpeed

In the AT24C08A datasheet, the information is indicated in Table 5 "AC Characteristics":

|                  |                      | 1.8- | volt | 1.8-volt 2.7, 5.0-volt |     |       |
|------------------|----------------------|------|------|------------------------|-----|-------|
| Symbol           | Parameter            | Min  | Max  | Min                    | Max | Units |
| f <sub>SCL</sub> | Clock Frequency, SCL |      | 100  |                        | 400 | kHz   |

It is indicated that the AT24C08A has an I2C Maximum Clock Frequency of 400kHz with some restriction of voltage. If you use the device between 2.7V and 5.0V, then it is 400kHz. If you use the device at 1.8V then it is 100kHz.

So, we configure EEPROM Conf.MaxI2CclockSpeed following the device voltage.

#### 3.3. Example of how to fill an EEPROM Conf of a EERAM device

The following example was performed on a 47L16 device.

```
const EEPROM_Conf EERAM47L16_Conf =
  .ChipAddress
                 = 0 \times A0,
                                              // Chip base address
                 = EEPROM_CHIP_ADDRESS_A2A1, // Device have A2 and A1 pins
  .ChinSelect
                = EEPROM_ADDRESS_2Bytes,
  .AddressType
                                              // Memory address takes 2 bytes
  .PageWriteTime = 25,
                                              // 25ms of page write
                = 2048,
 .PageSize
                                              // Page size is 2048 bytes
  .ArrayByteSize = 2048,
                                              // Memory size is 2048 bytes
  .MaxI2CclockSpeed = 1000000,
                                              // Max I2C SCL speed is 1MHz
```

#### 3.3.1. Fill the EEPROM\_Conf.ChipAddress

In the 47L16 datasheet, the information is indicated at §2.2 "Device Addressing" in the Figure 2-3:

| Operation              | Op<br>Code | Chip<br>Select | R/W<br>Bit |  |
|------------------------|------------|----------------|------------|--|
| SRAM Read              | 1010       | A2 A1 0        | 1          |  |
| SRAM Write             | 1010       | A2 A1 0        | 0          |  |
| Control Register Read  | 0011       | A2 A1 0        | 1          |  |
| Control Register Write | 0011       | A2 A1 0        | 0          |  |

The memory Chip Address we are looking for is the SRAM. The Control Register is not what we are looking for.

We are looking for the fixed information called here "Op Code", without Chip Select bits (A2 and A1). The  $R/\overline{W}$  bit need to be ignored too. Take care that the normally A0 pin is not used and always at '0', this have to be reported in the ChipAddress.

These bits have to be set to '0'. So, we configure EEPROM Conf. ChipAddress with 0b10100000 or 0xA0.

#### 3.3.2. Fill the EEPROM\_Conf.ChipSelect

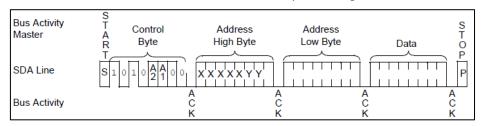
Here we are looking for which chip select bits are present on this device. In the 47L16 datasheet, the information is indicated at §2.2 "Device Addressing" in the Figure 2-3 (see §3.3.1):

The device has A1, and A2 as user configurable chip select. They are all configurable at '0' or '1'.

So, we configure EEPROM\_Conf.ChipSelect with EEPROM\_CHIP\_ADDRESS\_A2A1.

#### 3.3.3. Fill the EEPROM\_Conf.AddressType

In the 47L16 datasheet, the information is indicated at §2.3 "SRAM Array" in the Figure 2-4:



The address takes 2 bytes. The first is for "Address High Byte" and the second is for "Address Low Byte". So, we need to configure EEPROM\_Conf.AddressType with EEPROM\_ADDRESS\_2Bytes.

#### 3.3.4. Fill the EEPROM Conf.PageWriteTime

In the 47L16 datasheet, the information is indicated at §1.0 "ELECTRICAL CHARACTERISTICS" in the Table 1-2:

| AC CHARACTERISTICS |        |                          | 47LXX:<br>47CXX:<br>Industrial (I)<br>Automotive | VCC<br>TAM | 3.6V<br>5.5V<br>to +85°C<br>to +125°C |            |
|--------------------|--------|--------------------------|--|------------|---------------------------------------|------------|
| Param.<br>No.      | Symbol | Characteristic           | Min.   | Max.       | Units                                 | Conditions |
| 16                 | TSTORE | Store Operation Duration | _  | 25         | ms                                    | 47X16      |
|                    |        |                          | _  | 8          | ms                                    | 47X04      |

The parameter 16 indicate that the maximum write cycle time is 25ms for the 47X16. We need to always use the maximum time. So, we configure EEPROM\_Conf.PageWriteTime with 25. In reality, due to the operation of SRAM, it will take no time to store data. You can set this parameter to 0.

#### 3.3.5. Fill the EEPROM\_Conf.PageSize

In the 47L16 device, when the driver communicates with it, it always sees the SRAM, never the EEPROM. So, there is no page with this component, thus we configure EEPROM\_Conf.PageSize with 2048 (see §3.3.6) which is the byte memory size of the SRAM. Never set '0'.

#### 3.3.6. Fill the EEPROM\_Conf.ArrayByteSize

In the 47L16 datasheet, the information is indicated in the "Device Selection Table" of the device in the first page of the datasheet:

| Part Number | Density (bits) | Vcc<br>Range | Max. Clock<br>Frequency | Temperature<br>Ranges | Packages  |
|-------------|----------------|--------------|-------------------------|-----------------------|-----------|
| 47L04       | 4K             | 2.7-3.6V     | 1 MHz                   | I, E                  | P, SN, ST |
| 47C04       | 4K             | 4.5-5.5V     | 1 MHz                   | I, E                  | P, SN, ST |
| 47L16       | 16K            | 2.7-3.6V     | 1 MHz                   | I, E                  | P, SN, ST |
| 47C16       | 16K            | 4.5-5.5V     | 1 MHz                   | I, E                  | P, SN, ST |

It is indicated 16 Kbits. This memory is  $16 \times 1024 = 16384$  bits  $\rightarrow 16384/8 = 2048$  bytes. So, we configure EEPROM\_Conf.ArrayByteSize with 2048.

#### 3.3.7. Fill the EEPROM Conf.MaxI2CclockSpeed

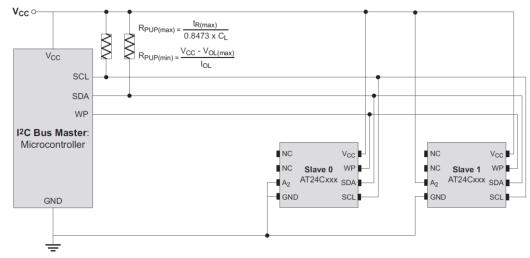
In the 47L16 datasheet, the information is indicated in the Device Selection Table of the device in the first page of the datasheet:

|               |        | 47CXX: VC<br>Industrial (I): TAI |      | Vcc = 2.7V to 3.6V<br>Vcc = 4.5V to 5.5V<br>TAMB = -40°C to +85°C<br>TAMB = -40°C to +125°C |       |            |
|---------------|--------|----------------------------------|------|---|-------|------------|
| Param.<br>No. | Symbol | Characteristic                   | Min. | Max.  | Units | Conditions |
| 1             | FCLK   | Clock Frequency                  | _    | 1000  | kHz   |            |

It is indicated that the 47L16 has an I2C Maximum Clock Frequency of 1MHz with no restriction of voltage. So, we configure EEPROM\_Conf.MaxI2CclockSpeed with 1000000.

#### 3.4. Example of how to fill an EEPROM\_Conf of dual EEPROM devices in series

The following example was performed with two AT24CM02 devices on the same bus. One with A2 at '0' and the other with A2 as '1'. Schematic of the connection:



#### 3.4.1. One device configuration

Here is the configuration of one AT24CM02 device (see §3.2 to understand how to configure a device):

```
const EEPROM_Conf AT24CM02_Conf =
  .ChipAddress
                 = 0xA0,
                                                    // Chip base address
                 = EEPROM_CHIP_ADDRESS_A2,
  .ChipSelect
                                                   // Device have only the A2 pins
  .AddressType = EEPROM_ADDRESS_2Byte_plus_A1A0, // Memory address takes 2 bytes + A0 and A1 pin function
  .PageWriteTime = 10,
                                                    // 10ms of page write
  .PageSize
                = 256,
                                                   // Page size is 256 bytes
  .ArrayByteSize = 1024/*Pages*/ *256,
                                                    // Memory size is 1024*256 = 262144 bytes
  .MaxI2CclockSpeed = 1000000,
                                                    // Max I2C SCL speed is 1MHz
};
```

#### 3.4.2. Two devices configuration to see EEPROM as 1 bank of memory

Here is the configuration of two AT24CM02 device as 1 memory bank:

```
const EEPROM Conf DualAT24CM02 Conf =
  .ChipAddress
                 = 0 \times A0,
                                                      // Chip base address
  .ChipSelect = EEPROM_NO_CHIP_ADDRESS_SELECT,
                                                      // The virtual device have no chip address left
  .AddressType = EEPROM_ADDRESS_2Byte_plus_A2A1A0, // Memory address takes 2 bytes + A0, A1 and A2 pin function
  .PageWriteTime = 10,
                                                      // 10ms of page write (remain the same)
                                                      // Page size is 256 bytes (remain the same)
  .PageSize
                = 256
  .ArrayByteSize = 2*1024/*Pages*/ *256,
                                                      // Memory size is 2*1024*256 = 524288 bytes
  .MaxI2CclockSpeed = 1000000,
                                                      // Max I2C SCL speed is 1MHz (remain the same)
};
```

The EEPROM\_Conf.ChipAddress, EEPROM\_Conf.PageWriteTime, EEPROM\_Conf.PageSize and EEPROM\_Conf.MaxI2CclockSpeed are the same and are not changed.

We will use the A2 pin as the  $19^{th}$  address pin, the "virtual device" will have no chip address pin left so, EEPROM\_Conf.ChipSelect is set to EEPROM\_NO\_CHIP\_ADDRESS\_SELECT, and EEPROM\_Conf.AddressType with EEPROM\_ADDRESS\_2Byte\_plus\_A2A1A0. With two same devices, the size of the new bank will double so, EEPROM\_Conf.ArrayByteSize is  $2 \times 262144 = 524288$  bytes.

#### 4. DEVICE CONFIGURATION

Each first parameter of a function is the device configuration. The purpose of this device configuration is to specify to the driver how and by which interface to communicate with the device selected. The device configuration type is EEPROM.

The EEPROM.fnI2C\_Init, EEPROM.fnI2C\_Transfer, and EEPROM.fnGetCurrentms are explained at §8.1.3 and an example at §10.

The EEPROM.Conf is the desired frequency of the I2C clock in Hertz. This allows the driver to verify the I2C speed.

The EEPROM.I2C ClockSpeed is the desired frequency of the I2C clock in Hertz. This allows the driver to verify the I2C speed.

The EEPROM.UserDriverData is a generic pointer to what the user need. It can be used as context or bringing information for the interface functions for example. This variable is never touch by the driver.

The EEPROM.AddrA2A1A0 is the chip address pin configuration of A2, A1, and A0 pins.

#### 4.1. Example

Example of driver configuration in a .c file:

```
struct EEPROM EEPROM24C08A_V71 =
  .UserDriverData = NULL,
  //--- EEPROM configuration
                  = &AT24C08A_Conf,
  .Conf
  //--- Driver configuration
  .I2C_ClockSpeed = 400000, // 400kHz
  //--- Interface driver call functions ---
  .InterfaceDevice = TWIHSO, // Here this point to the address memory of the peripheral TWIHSO
  .fnI2C_Init
                 = HardI2C_InterfaceInit_V71,
  .fnI2C_Transfer = HardI2C_Tranfert_V71,
  //--- Time call function -
  .fnGetCurrentms = GetCurrentms_V71,
  //--- Interface clocks --
  .AddrA2A1A0
                   = EEPROM_ADDR(0, 0, 1), // Here A2 = '0', A1 = '0', and A0 = '1'
};
```

Example of driver configuration in a .h file:

```
extern struct EEPROM EEPROM24C08A_V71;
#define EEPROM_24C08A &EEPROM24C08A_V71
```

#### 5. DEVICE INITIALIZATION

After configuring the device, you need to apply its configuration. To do this, it is pretty simple, first you need to call the <a href="Init\_EEPROM">Init\_EEPROM</a>() function with the <a href="EEPROM">EEPROM</a> struct. If all went well, the function would return <a href="ERR\_OK">ERR\_OK</a>.

After that, the device is ready to use.

#### 5.1. Example

Example of device initialization:

```
eERRORRESULT Error = Init_EEPROM(EEPROM_24C08A);
if (Error == ERR_OK)
{
   LOGTRACE("Device detected: 24C08A [1kB EEPROM (64x16)]");
}
```

This example is based on the example of configuration showed in §4.1.

#### 6. READ DATA FROM THE EEPROM

To read data from the EEPROM, just use the <a href="EEPROM\_ReadData">EEPROM\_ReadData</a>() function. The address can be any byte in the memory area, even inside a page. The size of data to read can be any value, even the full memory size.

The only limitation is that  $Address + Size \leq Size \ EEPROM$ .

#### 6.1. Example

Example of how to read data from the EEPROM.

```
uint32_t Address = 0x0000; // Address for the example
uint8_t ReadBuffer[16]; // Buffer for the example, it can be of any size
eERRORRESULT Error = EEPROM_ReadData(EEPROM_24C08A, Address, &ReadBuffer[0], sizeof(ReadBuffer));
// Test Error, Error should be ERR_OK if the read is complete without errors
// Do stuff
```

#### 7. WRITE DATA TO THE EEPROM

To write data to the EEPROM, just use the EEPROM\_WriteData() function. The address can be any byte in the memory area, even inside a page. The size of data to read can be any value, even the full memory size.

The only limitation is that  $Address + Size \leq Size \; EEPROM$ .

#### 7.1. Example

#### 7.1.1. Send message to the only one Transmit FIFO with INTO

Example of how to write data to the EEPROM.

```
uint32_t Address = 0x0000; // Address for the example
uint8_t WriteBuffer[16]; // Buffer for the example, it can be of any size
// Fill buffer with what you want
eERRORRESULT Error = EEPROM_WriteData(EEPROM_24C08A, Address, &WriteBuffer[0], sizeof(WriteBuffer));
// Test Error, Error should be ERR_OK if the write is complete without errors
// Do stuff
```

#### 8. CONFIGURATION STRUCTURES

#### 8.1. Device object structure

The EEPROM device object structure contains all information that is mandatory to work with a device. It is always the first parameter of each functions of the driver.

#### Source code:

```
typedef struct EEPROM EEPROM;

struct EEPROM
{
    void *UserDriverData;

    //--- EEPROM configuration ---
    const EEPROM_Conf *Conf;

    //--- Interface clocks ---
    uint32_t I2C_clockSpeed;

    //--- Interface driver call functions ---
    void *InterfaceDevice;

EEPROM_I2CInit_Func fnI2C_Init;

EEPROM_I2CTranfert_Func fnI2C_Transfer;

    //--- Time call function ---
    GetCurrentms_Func fnGetCurrentms;

    //--- Device address ---
    uint8_t AddrA2A1A0;
};
```

#### 8.1.1. Data fields

#### void \*UserDriverData

Optional, can be used to store driver data related to the project and the device or NULL. This field is not used or modified by the driver.

#### const EEPROM\_Conf \*Conf

This is the EEPROM configuration, this parameter is mandatory.

#### Type

struct

EEPROM\_Conf

#### uint32\_t I2C\_ClockSpeed

Clock frequency of the I2C interface in Hertz.

#### void \*InterfaceDevice

This is the pointer that will be in the first parameter of all interface call functions.

#### EEPROM\_I2CInit\_Func fnI2C\_Init

This function will be called at driver initialization to configure the I2C interface driver.

#### Type

typedef eERRORRESULT (\*EEPROM\_I2CInit\_Func)(void \*, const uint32\_t)

#### Initial value / default

This function must point to a function else a <a href="ERR\_\_PARAMETER\_ERROR">ERR\_\_PARAMETER\_ERROR</a> is returned by the function <a href="Init\_EEPROM()">Init\_EEPROM()</a>.

#### EEPROM\_I2CTranfert\_Func fnI2C\_Transfer

This function will be called when the driver needs to transfer data over the I2C communication with the device.

#### Type

typedef eERRORRESULT (\*EEPROM\_I2CTranfert\_Func)(void \*, const uint8\_t, uint8\_t \*, size\_t, bool, bool)

#### Initial value / default

This function must point to a function else an <a href="ERR\_\_PARAMETER\_ERROR">ERR\_\_PARAMETER\_ERROR</a> is returned when using a function that require to communicate with the device.

#### GetCurrentms Func fnGetCurrentms

This function will be called when the driver needs to get current millisecond. Some functions need a timeout, without, they can be stuck forever.

#### Type

typedef uint32 t (\*GetCurrentms Func)(void)

#### Initial value / default

This function has to point to a function else an <a href="ERR\_PARAMETER\_ERROR">ERR\_PARAMETER\_ERROR</a> is returned by the functions <a href="EEPROM ReadData()">EEPROM WriteData()</a>.

#### uint8\_t AddrA2A1A0

Device configurable address A2, A1, and A0. You can use the macro EEPROM\_ADDR() to help filling this parameter. Only these 3 lower bits are used: ....210\_ where 2 is A2, 1 is A1, 0 is A0. '.' and '\_' are fixed by device. If the device has a fixed A2, A1, and/or A0 then set them in the macro EEPROM\_ADDR().

#### **8.1.2.** Defines

#### #define EEPROM\_ADDR(A2, A1, A0)

Generate the EEPROM chip configurable address following the state of A0, A1, and A2. You shall set '1' (when corresponding pin is connected to +V) or '0' (when corresponding pin is connected to Ground) on each parameter. If the device has a fixed A2, A1, and/or A0 then set them in this macro.

#### 8.1.3. Driver interface handle functions

```
eERRORRESULT (*EEPROM_I2CInit_Func)(
void *pIntDev,

const uint32_t sclFreq)
```

Function for interface driver initialization of the EEPROM. This function will be called at driver initialization to configure the interface driver.

#### **Parameters**

Input \*pIntDev Is the EEPROM.InterfaceDevice of the device that call the interface initialization
Input sclFreq Is the SCL frequency in Hz to set at the interface initialization

#### Return

Returns an *eERRORRESULT* value enumerator dependent of how the return error is implemented by the user. It is recommended, during the implement of the pointer interface function, to return only ERR\_I2C\_NACK, ERR\_I2C\_NACK\_DATA, ERR\_I2C\_PARAMETER\_ERROR, ERR\_I2C\_COMM\_ERROR, ERR\_I2C\_COMFIG\_ERROR, ERR\_I2C\_TIMEOUT, ERR\_I2C\_DEVICE\_NOT\_READY, ERR\_I2C\_INVALID\_ADDRESS, ERR\_I2C\_INVALID\_COMMAND, or ERR\_I2C\_FREQUENCY\_ERROR when there is an error and ERR\_OK when all went fine.

```
eERRORRESULT (*EEPROM_I2CTranfert_Func)(
    void *pIntDev,
    const uint8_t deviceAddress,
    uint8_t *data,
    size_t byteCount,
    bool start,
    bool stop)
```

Function for interface transfer of the EEPROM. This function will be called when the driver needs to transfer data over the I2C communication with the device. Can be a read of data or a transmit of data. It also indicates if it needs a start and/or a stop.

#### **Parameters**

| Input  | *pIntDev      | Is the EEPROM.InterfaceDevice of the device that call the I2C transfer   |
|--------|---------------|--|
| Input  | deviceAddress | Is the device address on the bus (8-bits only). The LSB bit indicate if it is a I2C Read (bit at '1') or a I2C Write (bit at '0')  |
| In/Out | *data         | Is a pointer to memory data to write in case of I2C Write, or where the data received will be stored in case of I2C Read (can be NULL if no data transfer other than chip address) |
| Input  | byteCount     | Is the byte count to write over the I2C bus or the count of byte to read over the bus  |
| Input  | start         | Indicate if the transfer needs a start (in case of a new transfer) or restart (if the previous transfer has not been stopped)  |
| Input  | stop          | Indicate if the transfer needs a stop after the last byte sent   |

#### Return

Returns an *eERRORRESULT* value enumerator dependent of how the return error is implemented by the user. It is recommended, during the implement of the pointer interface function, to return only ERR\_I2C\_NACK, ERR\_I2C\_NACK\_DATA, ERR\_I2C\_PARAMETER\_ERROR, ERR\_I2C\_COMM\_ERROR, ERR\_I2C\_CONFIG\_ERROR, ERR\_I2C\_TIMEOUT, ERR\_I2C\_DEVICE\_NOT\_READY, ERR\_I2C\_INVALID\_ADDRESS, ERR\_I2C\_INVALID\_COMMAND, or ERR\_I2C\_FREQUENCY\_ERROR when there is an error and ERR\_OK when all went fine.

#### uint32 t (\*GetCurrentms\_Func)(void)

Function that gives the current millisecond of the system to the driver. This function will be called when the driver needs to get current millisecond.

#### Return

Returns the current millisecond of the system

#### 8.2. EEPROM configuration object structure

The EEPROM configuration object structure contains all information that is mandatory to work with the memory of the device. Source code:

```
typedef struct EEPROM_Conf
{
    uint8_t ChipAddress;
    eEEPROM_ChipSelect ChipSelect;
    eEEPROM_AddressType AddressType;
    uint8_t PageWriteTime;
    uint16_t PageSize;
    uint32_t ArrayByteSize;
    uint32_t MaxI2CclockSpeed;
} EEPROM_Conf;
```

#### 8.2.1. Data fields

#### uint8\_t ChipAddress

This is the base chip address. Generally, it is 0xA0, this is the general EEPROM I2C address.

#### eEEPROM\_ChipSelect ChipSelect

Indicate which chip select pins are used by the chip.

#### Type

enum eEEPROM\_ChipSelect

#### eEEPROM AddressType AddressType

Indicate the EEPROM address type.

#### Type

enum eEEPROM\_AddressType

#### uint8\_t PageWriteTime

Maximum time to write a page (for timeout) in millisecond.

#### uint16 t PageSize

This is the page size of the device memory in bytes.

#### uint32\_t ArrayByteSize

This is the memory total size in bytes.

#### uint32\_t MaxI2CclockSpeed

This is the maximum I2C SCL clock speed of the device in Hertz.

#### 8.2.2. Enumerators

#### enum eEEPROM\_ChipSelect

Enumerator of all possible user configurable chip address selection pin that the device can have.

#### **Enumerator**

| EEPROM_NO_CHIP_ADDRESS_SELECT | 0x00 | No chip select address                           |
|-------------------------------|------|--|
| EEPROM_CHIP_ADDRESS_A0        | 0x01 | User configurable chip select use A0             |
| EEPROM_CHIP_ADDRESS_A1        | 0x02 | User configurable chip select use A1             |
| EEPROM_CHIP_ADDRESS_A2        | 0x04 | User configurable chip select use A2             |
| EEPROM_CHIP_ADDRESS_A1A0      | 0x03 | User configurable chip select use A1, and A0     |
| EEPROM_CHIP_ADDRESS_A2A0      | 0x05 | User configurable chip select use A2, and A0     |
| EEPROM_CHIP_ADDRESS_A2A1      | 0x06 | User configurable chip select use A2, and A1     |
| EEPROM_CHIP_ADDRESS_A2A1A0    | 0x07 | User configurable chip select use A2, A1, and A0 |
|                               |      |  |

#### enum eEEPROM\_AddressType

Enumerator of all possible address configuration type.

#### **Enumerator**

| ilanici ato:                     |      |   |
|----------------------------------|------|---|
| EEPROM_ADDRESS_1Byte             | 0x01 | EEPROM Address is 8-bits: S (1010A <sub>2</sub> A <sub>1</sub> A <sub>0</sub> _) (xxxxxxxx)               |
| EEPROM_ADDRESS_1Byte_plus_A0     | 0x21 | EEPROM Address is 9-bits: S (1010A <sub>2</sub> A <sub>1</sub> x _) (xxxxxxxxx)                           |
| EEPROM_ADDRESS_1Byte_plus_A1A0   | 0x61 | EEPROM Address is 10-bits: S (1010A <sub>2</sub> x x _) (xxxxxxxxx)                                       |
| EEPROM_ADDRESS_1Byte_plus_A2A1A0 | 0xE1 | EEPROM Address is 11-bits: S (1010x x x _) (xxxxxxxxx)  |
| EEPROM_ADDRESS_2Bytes            | 0x02 | EEPROM Address is 16-bits: S (1010A <sub>2</sub> A <sub>1</sub> A <sub>0</sub> _) (xxxxxxxxx) (xxxxxxxxx) |
| EEPROM_ADDRESS_2Byte_plus_A0     | 0x22 | EEPROM Address is 17-bits: S (1010A <sub>2</sub> A <sub>1</sub> x _) (xxxxxxxxx) (xxxxxxxxx)              |
| EEPROM_ADDRESS_2Byte_plus_A1A0   | 0x62 | EEPROM Address is 18-bits: S (1010A <sub>2</sub> x x _) (xxxxxxxx) (xxxxxxxxx)                            |
| EEPROM_ADDRESS_2Byte_plus_A2A1A0 | 0xE2 | EEPROM Address is 19-bits: S (1010x x x _) (xxxxxxxxx) (xxxxxxxxxxxxxxxxxx                                |
| EEPROM_ADDRESS_3Bytes            | 0x03 | EEPROM Address is 24-bits: S (1010A <sub>2</sub> A <sub>1</sub> A <sub>0</sub> _) (xxxxxxxxx) (xxxxxxxxx) |
|                                  |      | (xxxxxxxx)  |
| EEPROM_ADDRESS_3Byte_plus_A0     | 0x23 | EEPROM Address is 25-bits: S (1010A <sub>2</sub> A <sub>1</sub> x _) (xxxxxxxx) (xxxxxxxxx)               |
|                                  |      | (xxxxxxxx)  |
| EEPROM_ADDRESS_3Byte_plus_A1A0   | 0x63 | EEPROM Address is 26-bits: S (1010A <sub>2</sub> x x _) (xxxxxxxxx) (xxxxxxxxxx)                          |
|                                  |      | (xxxxxxxx)  |
| EEPROM_ADDRESS_3Byte_plus_A2A1A0 | 0xE3 | EEPROM Address is 27-bits: S (1010x x x _) (xxxxxxxxx) (xxxxxxxxxxxxxxxxxx                                |
|                                  |      | (xxxxxxxx)  |
| EEPROM_ADDRESS_4Bytes            | 0x04 | EEPROM Address is 32-bits: S (1010A <sub>2</sub> A <sub>1</sub> A <sub>0</sub> _) (xxxxxxxxx) (xxxxxxxxx) |
|                                  |      | (xxxxxxxx) (xxxxxxxxx)  |
|                                  |      |   |

#### 8.3. Function's return error enumerator

#### enum eERRORRESULT

There is only one error code at the same time returned by the functions. The only code that indicates that all went fine is ERR\_OK.

#### **Enumerator**

| illullierator           |     |  |
|-------------------------|-----|--|
| ERR_OK                  | 0   | Succeeded  |
| ERRNO_DEVICE_DETECTED   | 1   | No device detected                                     |
| ERROUT_OF_RANGE         | 2   | Value out of range                                     |
| ERROUT_OF_MEMORY        | 6   | Out of memory  |
| ERRDEVICE_TIMEOUT       | 8   | Device timeout   |
| ERRPARAMETER_ERROR      | 9   | Parameter error  |
| ERRNOT_READY            | 10  | Device not ready                                       |
| ERRI2C_NACK             | 210 | Received a I2C not acknowledge                         |
| ERRI2C_NACK_DATA        | 211 | Received a I2C not acknowledge while transferring data |
| ERRI2C_PARAMETER_ERROR  | 212 | I2C parameter error                                    |
| ERRI2C_COMM_ERROR       | 213 | I2C communication error                                |
| ERRI2C_CONFIG_ERROR     | 214 | I2C configuration error                                |
| ERRI2C_TIMEOUT          | 215 | I2C communication timeout                              |
| ERRI2C_DEVICE_NOT_READY | 216 | I2C device not ready                                   |
| ERRI2C_INVALID_ADDRESS  | 217 | I2C invalid address                                    |
| ERRI2C_INVALID_COMMAND  | 218 | I2C invalid command                                    |
| ERRI2C_FREQUENCY_ERROR  | 219 | I2C frequency error                                    |
|                         |     |  |

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#### 9. DRIVER'S FUNCTIONS

Here is the use of all functions related to the driver.

#### 9.1. Initialization

#### eERRORRESULT Init\_EEPROM( EEPROM \*pComp)

This function initializes the EEPROM driver and call the initialization of the interface driver (I2C). It also checks the presence of the device.

#### **Parameters**

Input \*pComp Is the pointed structure of the device to be initialized

#### Return

Returns an *eERRORRESULT* value enumerator. Below are some returned by the function itself but not errors returned by called functions.

- ERR\_\_PARAMETER\_ERROR when pComp or pComp->pConf is NULL, or Interface functions are NULL
- ERR I2C FREQUENCY ERROR when pComp->I2C ClockSpeed > pComp->Conf->MaxI2CclockSpeed
- ERR\_NO\_DEVICE\_DETECTED when no communication with the device is possible

#### bool **EEPROM\_IsReady**(EEPROM \***pComp**)

Poll the acknowledge from the EEPROM.

#### **Parameters**

Input \*pComp Is the pointed structure of the device to be used

Return

Returns 'true' if ready else 'false'

#### 9.2. Read data

```
eERRORRESULT EEPROM_ReadData(
    EEPROM *pComp,
    uint32_t address,
    uint8_t* data,
    size_t size)
```

This function reads data from the EEPROM area of a EEPROM device.

#### **Parameters**

Input \*pComp Is the pointed structure of the device to be used Input address Is the address to read (can be inside a page)
Output \*data Is where the data will be stored
Input size Is the size of the data array to read

#### Return

Returns an *eERRORRESULT* value enumerator.

- ERR\_\_PARAMETER\_ERROR when pComp, pComp->Conf or data is NULL, or Interface functions are NULL, or Address is too high
- ERR\_\_OUT\_OF\_MEMORY when you want to send too many data at the address specified or address is too high for the device
- ERR\_\_DEVICE\_TIMEOUT when it takes more than pComp->Conf->PageWriteTime+1 to write data to a page

#### 9.3. Write data

```
eERRORRESULT EEPROM_WriteData(
EEPROM *pComp,
Uint32_t address,
uint8_t* data,
size_t size)
```

This function writes data to the EEPROM area of a EEPROM device.

#### **Parameters**

Input \*pComp Is the pointed structure of the device to be used

Input address Is the address where data will be written (can be inside a page)

Input \*data Is the data array to store

Input size Is the size of the data array to write

#### Return

Returns an *eERRORRESULT* value enumerator.

- ERR\_\_PARAMETER\_ERROR when pComp, pComp->Conf or data is NULL, or Interface functions are NULL, or Address is too high
- ERR\_OUT\_OF\_MEMORY when you want to send too many data at the address specified or address is too high for the device
- ERR\_\_DEVICE\_TIMEOUT when it takes more than pComp->Conf->PageWriteTime+1 to write data to a page

#### 10. EXAMPLE OF DRIVER INTERFACE HANDLE FUNCTIONS

This is an extract from the project for the SAMV71 Xplained Ultra board.

Example of driver interface handle functions in a .c file:

```
// Get millisecond
//==:
uint32_t GetCurrentms_V71(void)
{
 return msCount;
}
// Hardware I2C driver interface configuration for the ATSAMV71
eERRORRESULT HardI2C_InterfaceInit_V71(void *pIntDev, const uint32_t sclFreq)
  if (pIntDev == NULL) return ERR__I2C_PARAMETER_ERROR;
 if (I2Cconfigured) return ERR_OK;
 //--- Configuration of the TWI interface ---
 twihs options t opt;
 opt.speed = sclFreq;
 if (twihs_master_setup(BOARD_AT24MAC_TWIHS, &opt) != TWIHS_SUCCESS) return ERR__I2C_CONFIG_ERROR;
  //--- Clear receive buffer -
 uint8_t Data = BOARD_AT24MAC_TWIHS_INSTANCE->TWIHS_RHR;
 (void)Data; // Unused data
  //--- clear registers
 Data = BOARD_AT24MAC_TWIHS_INSTANCE->TWIHS_SR;
 (void)Data; // Unused data
 I2Cconfigured = true;
 return ERR_OK;
//-----
// Hardware I2C - Transfer data through an I2C communication for the ATSAMV71
eERRORRESULT HardI2C_Tranfert_V71(void *pIntDev, const uint8_t deviceAddress, uint8_t *data, size_t byteCount, bool
start, bool stop)
 if (pIntDev == NULL) return ERR__SPI_PARAMETER_ERROR;
 if (data == NULL) return ERR__SPI_PARAMETER_ERROR;
                                    // MCU specific: #define TWIHS0 ((Twihs*)0x40018000U) // (TWIHS0) Base Address
 Twihs *I2C = (Twihs *)pIntDev;
 uint32_t Status;
 uint32_t Timeout = TWIHS_TIMEOUT;
 bool DeviceWrite = ((deviceAddress & 0x01) == 0);
 I2C->TWIHS\_MMR = 0;
 I2C->TWIHS_MMR = TWIHS_MMR_DADR(deviceAddress >> 1) | (DeviceWrite ? 0 : TWIHS_MMR_MREAD);
 I2C->TWIHS_IADR = 0; // Not used
 I2C->TWIHS_CR = TWIHS_CR_MSEN | TWIHS_CR_SVDIS;
  //--- Device polling ? ---
 if ((data == NULL) || (byteCount <= 0))</pre>
                                                             // Device polling only
 { // Little hack because TWI of V71 does not support device polling without using SMBus
   I2C->TWIHS_CR |= TWIHS_CR_SMBEN + TWIHS_CR_PECDIS;
                                                            // Enable SMBus
   I2C->TWIHS_CR |= TWIHS_CR_QUICK;
                                                             // Start the polling with a quick command
   Timeout = TWIHS_TIMEOUT;
                                                             // Wait the polling to finish
   while (true)
     Status = I2C->TWIHS_SR;
     if ((Status & TWIHS_SR_NACK) > 0) return ERR__I2C_NACK;
     if (!Timeout--) return ERR__I2C_TIMEOUT;
                                                             // Timeout ? return an error
     if ((Status & TWIHS_SR_TXCOMP) > 0) break;
   return ERR OK;
```

```
//--- Transfer data ---
if (start) I2C->TWIHS_CR |= TWIHS_CR_START;
                                                                 // Send a start if asked
if (DeviceWrite) // Device write
  while (true)
  {
    Status = I2C->TWIHS_SR;
    if ((Status & TWIHS_SR_NACK) > 0) return ERR__I2C_NACK_DATA;
    if (!Timeout--) return ERR__I2C_TIMEOUT;
if ((Status & TWIHS_SR_TXRDY) == 0) continue;
                                                               // Timeout ? return an error
    Timeout = TWIHS_TIMEOUT;
    if (byteCount == 0) break;
                                                                 // No data remaining to send, then break the loop
    I2C->TWIHS_THR = *data;
                                                                 // Send next data byte
    data++;
    byteCount--;
  if (stop) I2C->TWIHS_CR |= TWIHS_CR_STOP;
                                                                // Send a stop if asked
else // Device read
  while (byteCount > 0)
    if ((byteCount == 1) && stop)
    I2C->TWIHS_CR |= TWIHS_CR_STOP;
                                                                 // Last byte ? Send a stop if asked
    Timeout = TWIHS_TIMEOUT;
                                                                 // Wait the polling to finish
    while (true)
      Status = I2C->TWIHS_SR;
      if (!Timeout--) return ERR__I2C_TIMEOUT;
                                                                 // Timeout ? return an error
      if ((Status & TWIHS_SR_RXRDY) > 0) break;
    *data = I2C->TWIHS_RHR;
                                                                 // Get next data byte
    data++;
    byteCount--;
if (stop) while ((I2C->TWIHS_SR & TWIHS_SR_TXCOMP) == 0);
                                                                 // Wait until both holding register and internal
                                                                 // shifter are empty and STOP condition has been sent
return ERR_OK;
```

#### Example of driver interface handle functions in a .h file:

```
/*! @brief Get millisecond
st This function will be called when the driver needs to get current millisecond
uint32_t GetCurrentms_V71(void);
/*! @brief Hardware I2C driver interface configuration for the ATSAMV71
* This function will be called at driver initialization to configure the interface driver soft I2C
  @param[in] *pIntDev Is the EERAM47x16.InterfaceDevice of the device that call this function
  \operatorname{@param[in]} sclFreq Is the SCL frequency in Hz to set at the interface initialization
* @return Returns an #eERRORRESULT value enum
eERRORRESULT HardI2C_InterfaceInit_V71(void *pIntDev, const uint32_t sclFreq);
/*! @brief Hardware I2C - Transfer data through an I2C communication for the ATSAMV71
* This function will be called when the driver needs to transfer data over the I2C communication with the device
  Can be read data of transmit data. It also indicate if it needs a start and/or a stop
* @param[in] *pIntDev Is the Interface Device pointer of the device that call the I2C transfer
  @param[in] deviceAddress Is the device address on the bus (8-bits only). The LSB bit indicate if it is a I2C Read
(bit at '1') or a I2C Write (bit at '0')
 * @param[in,out] *data Is a pointer to memory data to write in case of I2C Write, or where the data received will be
stored in case of I2C Read (can be NULL if no data transfer other than chip address)
  @param[in] byteCount Is the byte count to write over the I2C bus or the count of byte to read over the bus
st @paramig[inig] start Indicate if the transfer needs a start (in case of a new transfer) or restart (if the previous
transfer have not been stopped)
 ' @param[in] stop Indicate if the transfer needs a stop after the last byte sent
* @return Returns an #eERRORRESULT value enum
eERRORRESULT <mark>HardI2C_Tranfert_V71</mark>(void *pIntDev, const uint8_t deviceAddress, uint8_t *data, size_t byteCount, bool
start, bool stop);
```